

KST812M3/M4/M5/M6/M7

General Purpose Transistor



1. Base 2. Emitter 3. Collector

PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a =25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	-50	V
V _{CEO}	Collector-Emitter Voltage	-40	V
V_{EBO}	Emitter-Base Voltage	-5	V
I _C	Collector Current	-100	mA
P _C	Collector Dissipation	350	mW
T _{STG}	Storage Temperature	150	°C

Refer to KST5088 for graphs

Electrical Characteristics T_a =25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
I _{CBO}	Collector Cut-off Current	V _{CB} = -40V, I _E =0		-100	nA
I _{EBO}	Emitter Cut-off Current	V_{EB} = -5V, I_{C} =0		-100	nA
h _{FE}	DC Current Gain : KST812M3 : KST812M4 : KST812M5 : KST812M6 : KST812M7	V _{CE} = -6V, I _C = -1mA	60 90 135 200 300	120 180 270 400 600	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = -30mA, I _B = -3mA		-0.5	V
V _{BE} (on)	Base-Emitter On Voltage	V _{CE} = -6V, I _C = -1mA		-0.8	V

Marking Code

Type	KST812M3	KST812M 4	KST812M5	KST812M6	KST812M7
Mark	M3	M4	M5	M6	M7

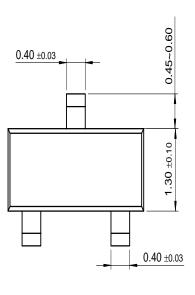
Marking

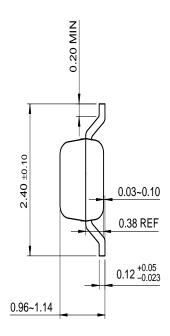


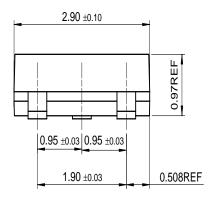
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Package Demensions

SOT-23







Dimensions in Millimeters

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